

## TO-220-3L Plastic-Encapsulate Diode

### MUR30H60CTB HYPERFAST RECTIFIER, FRED

#### MAIN CHARACTERISTICS

$I_o$	30(15×2)A
$V_{RRM}$	600V
$T_{rr}$	28ns
$T_j$	175℃
$V_{F(typ)}$	1.1V(@ $T_j=150℃$ )

#### FEATURES

- Ultrafast Recovery Times and Low Recovery Loss
- Low Forward Voltage
- Low Reverse Leakage Current

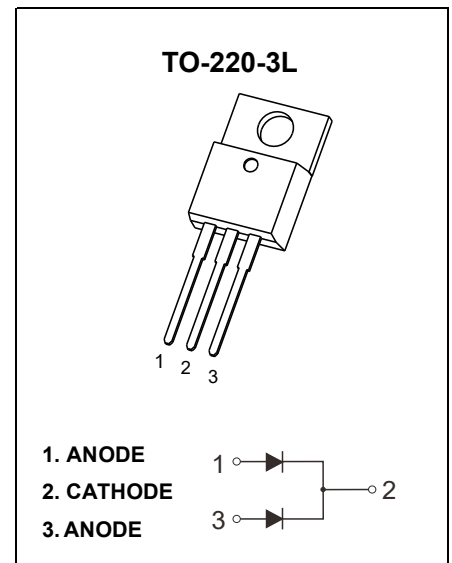
#### APPLICATIONS

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

#### MARKING



MUR30H60CTB = Device code  
 Solid dot = Green molding compound device  
 if none, the normal device  
 XXXX = Code



#### MAXIMUM RATINGS ( $T_c=25℃$ unless otherwise noted )

Symbol	Parameter	MUR30H60CTB	Unit
$V_{RRM}$	Peak Repetitive Reverse Voltage	600	V
$V_R$	DC Blocking Voltage		
$I_{F(AV)}$	Average rectified output current@ Per leg( $T_c=152℃$ )	15	A
	Average rectified output current@ Total device( $T_c=152℃$ )	30	
$I_{F(RMS)}$	RMS Forward Current( $T_c=152℃$ )	21	A
$I_{FSM}$	Non-Repetitive Surge Forward Current (8.3ms)	230	A
$P_D$	Power dissipation	100	W
$R_{\theta JC}$	Thermal Resistance From Junction to Case	1.5	℃/W
$T_j$	Operating Junction Temperature Range	-55 ~ +175	℃
$T_{stg}$	Storage Temperature Range	-55 ~ +175	℃

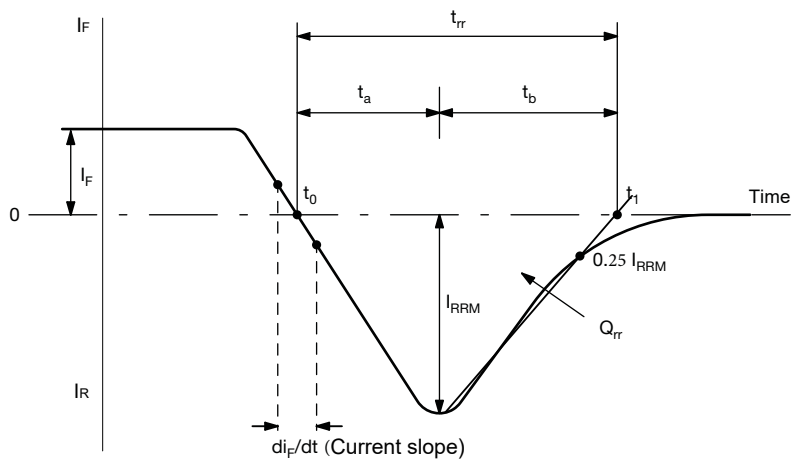
# Typical Characteristics

## ELECTRICAL CHARACTERISTICS ( $T_c=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_{(BR)}$	Reverse Voltage	$I_R=100\mu\text{A}$	600			V
$I_R$	Reverse Current	$V_R=600\text{V}$	$T_j=25^\circ\text{C}$		10	$\mu\text{A}$
			$T_j=150^\circ\text{C}$		500	$\mu\text{A}$
$V_F$	Forward Voltage	$I_F=15\text{A}$	$T_j=25^\circ\text{C}$	1.3	1.6	V
			$T_j=150^\circ\text{C}$	1.1		V
$C_{tot}$	Total Capacitance	$V_R=200\text{V}, f=1\text{MHz}$		15.4		pF
$t_{rr}$	Reverse Recovery time	$I_F=0.5\text{A}, I_R=1\text{A}, I_{rr}=0.25\text{A}$		30		ns
		$I_F=1\text{A}, V_R=30\text{V}, di_F/dt = 200\text{A}/\mu\text{s}$		28		ns

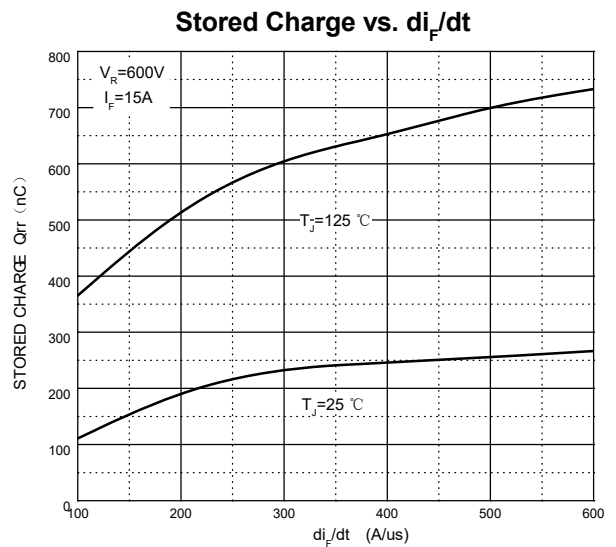
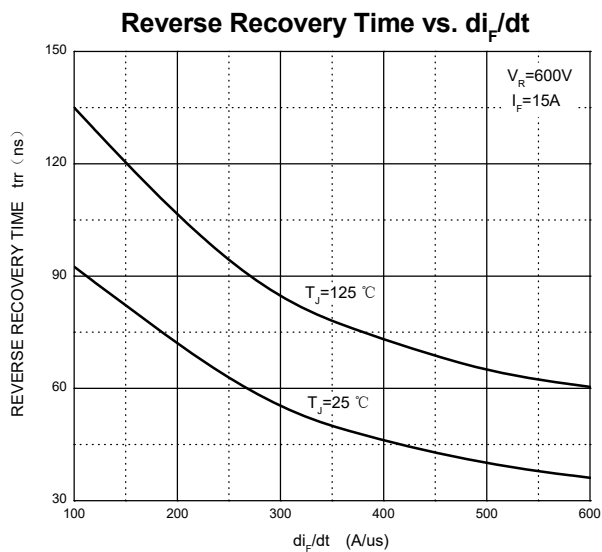
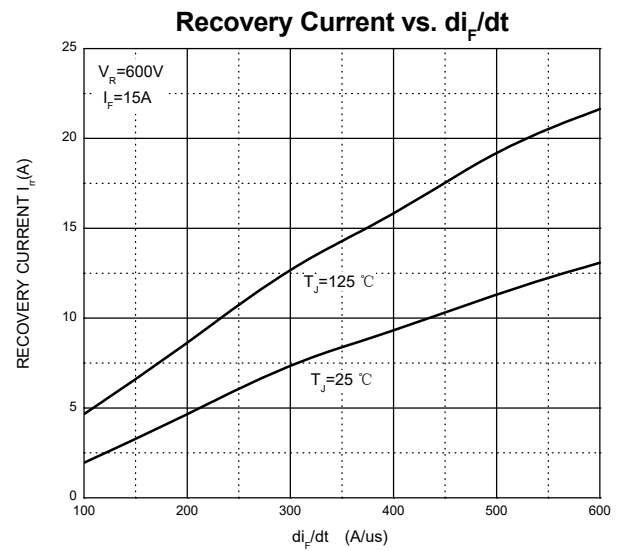
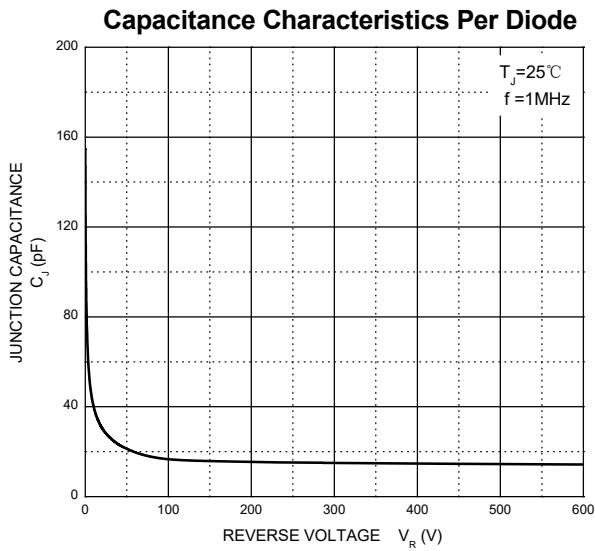
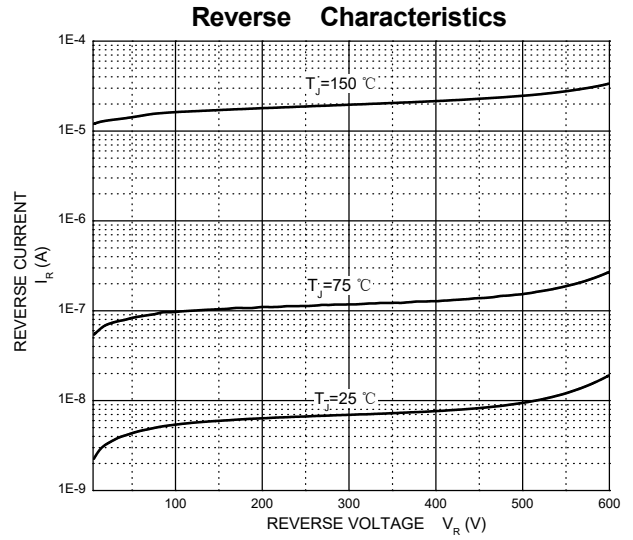
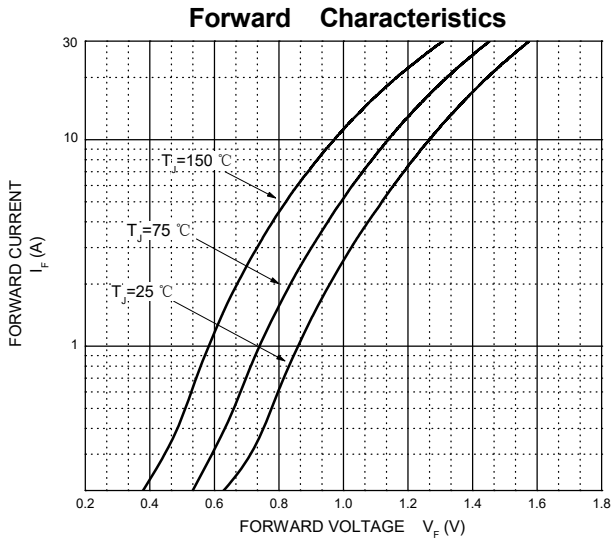
## ELECTRICAL CHARACTERISTICS ( $T_c=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$t_{rr}$	Reverse Recovery Time	$I_F=15\text{A}, V_R=600\text{V}, di_F/dt=200\text{A}/\mu\text{s}$		72		ns
$I_{RRM}$	Max. Reverse Recovery Current			4.6		A
$Q_{rr}$	Reverse Recovery Charge			198		nC
$t_{rr}$	Reverse Recovery Time	$I_F=15\text{A}, V_R=600\text{V}, di_F/dt=200\text{A}/\mu\text{s}, T_j=125^\circ\text{C}$		105		ns
$I_{RRM}$	Max. Reverse Recovery Current			8.5		A
$Q_{rr}$	Reverse Recovery Charge			525		nC
$t_{rr}$	Reverse Recovery Time	$I_F=15\text{A}, V_R=600\text{V}, di_F/dt=500\text{A}/\mu\text{s}, T_j=125^\circ\text{C}$		64		ns
$I_{RRM}$	Max. Reverse Recovery Current			19		A
$Q_{rr}$	Reverse Recovery Charge			703		nC



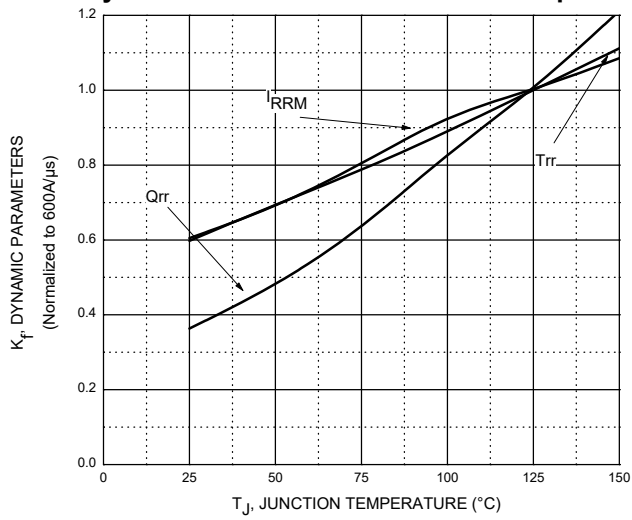
Reverse Recovery Waveform and Definitions

# Typical Characteristics

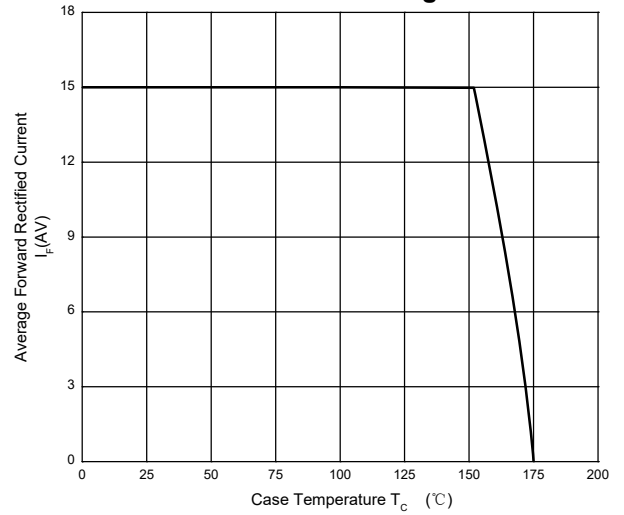


# Typical Characteristics

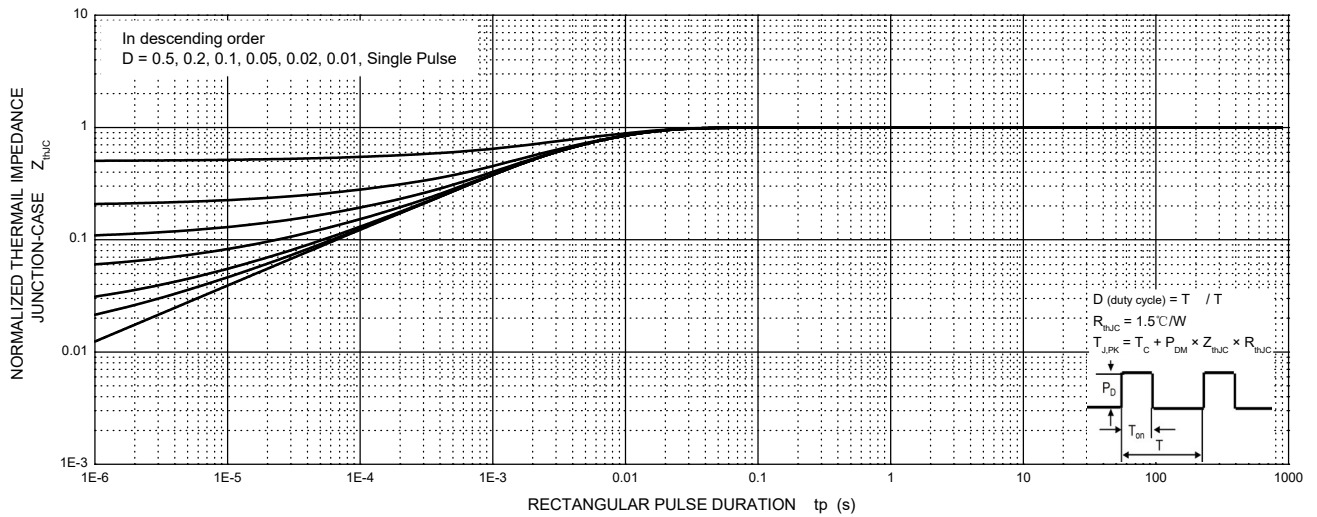
### Dynamic Parameters vs. Junction Temperature



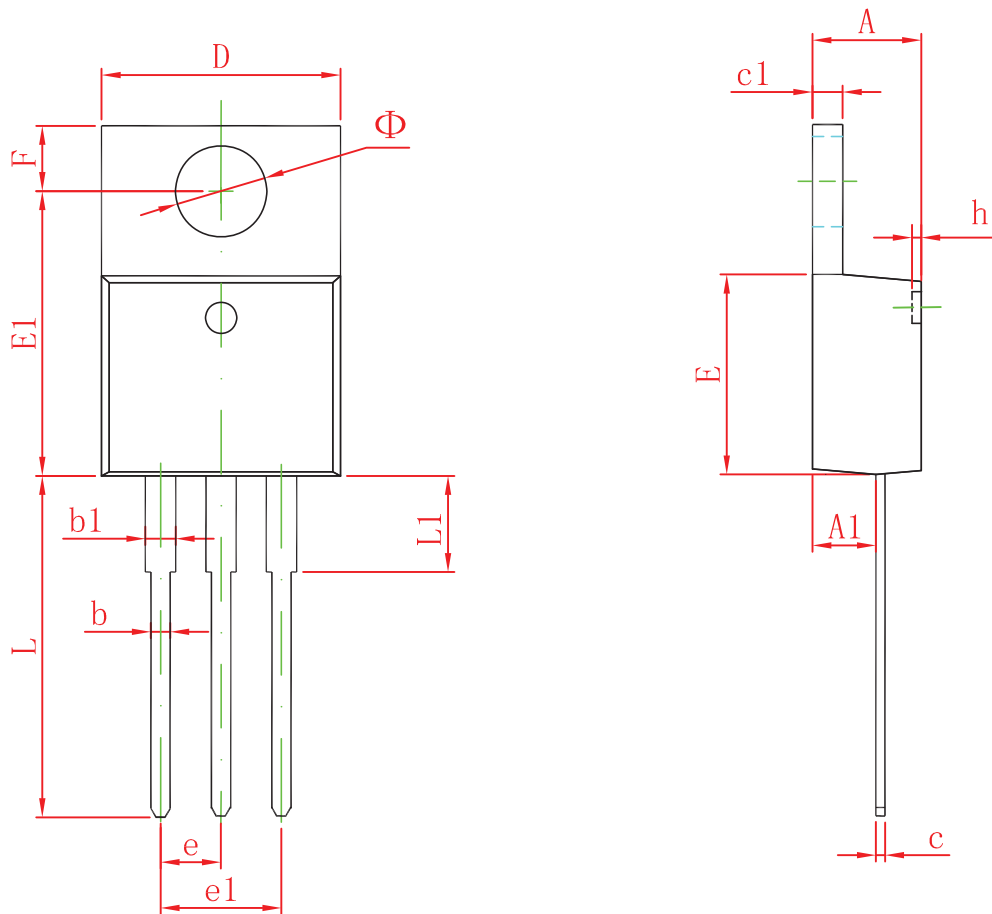
### Current Derating



### MUR30H60CTB Transient Thermal Impedance, Junction-Case



# TO-220-3L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	4.450	4.750	0.175	0.187
A1	2.520	2.820	0.099	0.111
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
c	0.300	0.500	0.012	0.020
c1	1.170	1.370	0.046	0.054
D	9.830	10.330	0.387	0.407
E	8.500	8.900	0.335	0.350
E1	12.050	12.650	0.474	0.498
e	2.540 TYP		0.100 TYP	
e1	4.900	5.200	0.192	0.205
F	2.540	2.940	0.100	0.116
h	0.100 TYP		0.004 TYP	
L	13.300	13.800	0.523	0.543
L1	3.540	3.940	0.139	0.155
$\Phi$	3.735	3.935	0.147	0.155